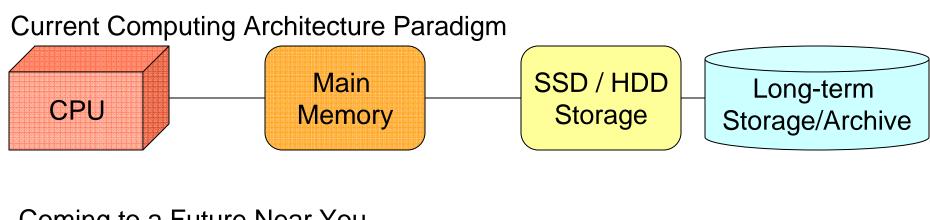
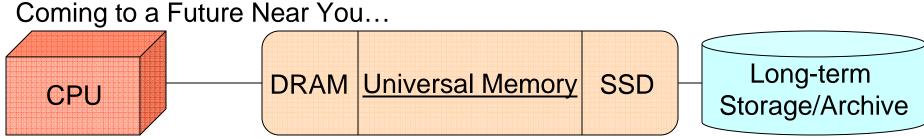


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# Disruptive Hybrid Storage: Fusing DRAM and NAND

# Current major focus for future of the industry => Universal or "Storage Class Memory"







Universal or "Storage Class Memory"

...could replace DRAM OR Flash OR Both





Fast
Non-Volatile
Endurance
Cheap
Low Power
Scalable
Dense
Reliable

BUT,

Will it have the speed of DRAM?

Will it be non-volatile like NAND Flash?



It's just not that easy...

Storage Class Memory (SCM) could replace DRAM and/or Flash some day, but likely not both at the same time.

SCM may have <u>some</u> of the desired characteristics, but likely <u>not most</u> of them right away.





A key question remains –



When will a <u>non-volatile</u>, <u>reliable</u> memory technology be available in a <u>speed</u> and <u>capacity</u> that's interesting for main memory and storage applications?

Could be around the corner, could be in 10 years.



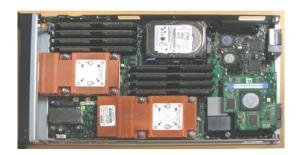
"If I knew I'd be rich." - Fujitsu CTO, Dr. Reger when asked what was the target after Flash

**Another Question:** 

Is this type of performance needed now?

The DIMM socket count in mainstream servers have gone from **four** to **eight** to **eighteen** between 2000 and 2010.





Need more memory space to contain application data growth.



## Т

#### The State of Things...

Is this type of performance needed now?

Systems also have growing storage capacity requirements but is now expected to be <u>FAST</u>! (usually leveraging NAND Flash through SSD's)

A main goal is to attempt to get the highest speed performance a majority of the time, while making very sure to preserve data integrity.

(Be careful not to progress too far without preserving data in non-volatile storage)



Is this type of performance needed now?

The answer is a RESOUNDING YES!

Without these issues solved, system solutions are required to continue to scale in expensive ways.







# As we await better solutions anything we can do <u>NOW</u>?



## "Hybrid Memory" addresses these problems



Memory products with devices of **one or more** types of memory technologies that leverage some of the beneficial characteristics of them all.

Today - DDR3 memory module with **DRAM** and **Flash** 



### **Hybrid Memory Modules**

# How is this different from many existing modules, PoP or other multi-tech devices?

- It operates as a <u>system</u> together vs. individual components
- Leverages beneficial device characteristics of both technologies to provide advantages to a shared system interface



#### **Hybrid Memory Modules**

Hybrid Modules should be used by systems **today** to take advantage of both the speed of DRAM and non-volatility of Flash.

This new persistence of data can be leveraged into very big advantages for many applications.

No need to commit cached application data to I/O storage, metadata is safe, and programs can stay in memory.



## Hybrid Memory – Key Components (example)

Many different implementation possibilities, but generally consists of:

DRAM

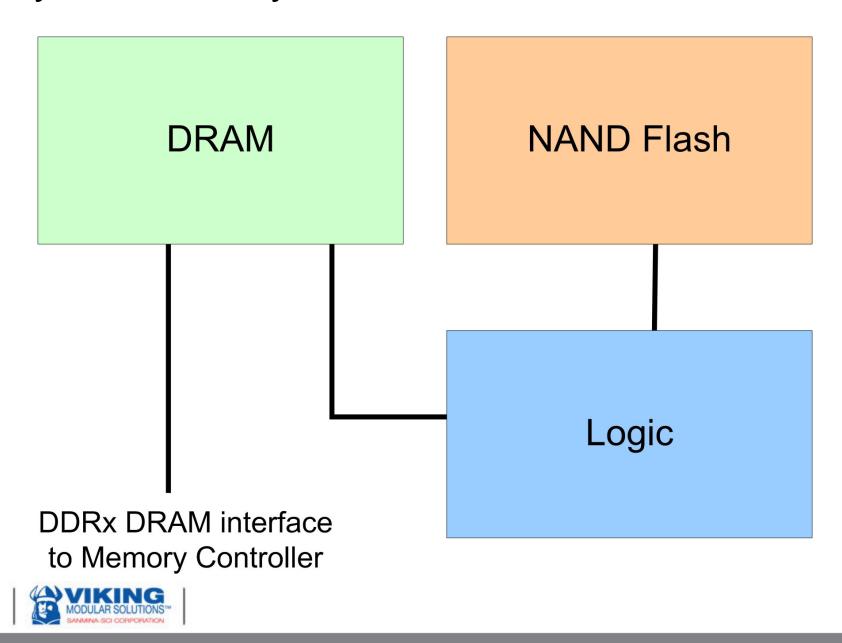
volatile 100ns latency NAND Flash

non-volatile 10us latency

Logic



### Hybrid Memory – One solution



## **Hybrid Memory**

#### Applications:

- Provides alternative to battery-backed DIMM's as well as large UPS holding up processors, storage, etc.
- Provides significant value to:
  - Storage
  - Server systems / Appliance Servers
  - SBB (Storage Bridge Bay) Storage Servers
- Enables interesting future applications work to be done



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